



CMOS Analog Switches

(Obsolete for non-hermetic. Use DG381B and DG390B as pin-for-pin replacements)

FEATURES

- ±15-V Input Range
- Low $r_{DS(on)}$: 30 Ω
- Single Supply Operation
- Pin and Function Compatible with the JFET DG180 Family

BENEFITS

- Full Rail-to-Rail Analog Signal Range Low Level Switching Circuits
- Minimizes Signal Error
- Low Power Dissipation

APPLICATIONS

- Programmable Gain Amplifiers
- Portable and Battery Powered Sytems

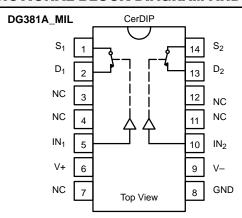
DESCRIPTION

The DG381A_MIL and DG390A_MIL monolithic CMOS analog switches were designed for applications in instrumentation, communications, and process control. This series is suited for applications requiring fast switching and nearly flat on-resistance over the entire voltage range.

Designed on Vishay Siliconix' PLUS-40 CMOS process, these devices achieve low power consumption (3.5 mW typical) and excellent on/off switch performance. These switches are ideal for battery powered applications, without sacrificing switching speed. Break-before-make switching action is guaranteed, and an epitaxial layer prevents latchup. Single supply operation is allowed by connecting the V- rail to

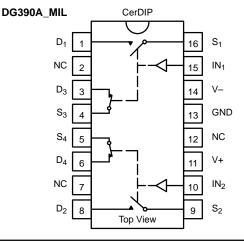
Each switch conducts equally well in both directions when on, and blocks up to the supply voltage when off. These switches are CMOS and quasi TTL logic compatible.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE			
Logic	Switch		
0	ON		
1	OFF		

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V



TRUTH TABLE				
Logic	SW ₁ , SW ₂	SW ₃ , SW ₄		
0	OFF	ON		
1	ON	OFF		

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V



ORDERING INFORMATION				
Temp Range	Part Number			
DG381A_MIL				
–55 to 125°C	14-Pin CerDIP	DG381AAK/883		
DG390A_MIL				
–55 to 125°C	16-Pin CerDIP	DG390AAK		
		DG390AAK/883		

ABSOLUTE MAXIMUM RATINGS

Voltages Refer	enced to V-				
V+					44 V
GND					25 V
Digital Inputsa,	$V_S, V_D \dots$			(V-) -2 V	to (V+) +2V or
			30 ı	mA, whiche	ever occurs first
Current, Any T	erminal Excep	ot S or D			30 mA
Continuous Cu	irrent, S or D				30 mA
(Pulsed at 1 m	s, 10% duty c	ycle max)			100 mA
Storage Tempe	erature	(AAK Suffix)			. –65 to 150°C

Power Dissipation ^b)	
14-Pin CerDIPc		825 mW

Notes:

- Signals on S_X, D_X, or IN_X exceeding V+ or V– will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
 All leads welded or soldered to PC Board.
 Derate 11 mW/°C above 75°C

SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

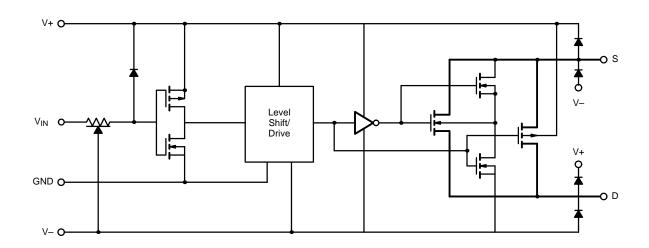


FIGURE 1.





SPECIFICATIONS ^a		Test Conditions Unless Specified V+ = 15 V, V- = -15 V V _{IN} = 0.8 V or 4 V ^f			Limits –55 to 125°C			
Parameter	Symbol			Temp ^b	Mind	Typ ^c	Maxd	Unit
Analog Switch		iiv		1	I.	1		
Analog Signal Range ^e	V _{ANALOG}			Full	-15		15	V
Drain-Source On-Resistance	r _{DS(on)}	V _D = ±10 V, I _S =	= –10 mA	Room Full		30	50 75	Ω
Source Off Leakage Current	I _{S(off)}	$V_S = \pm 14 \text{ V}, V_D$	= ∓14 V	Room Hot	-1 -100	±0.1	1 100	
Drain Off Leakage Current	I _{D(off)}	$V_S = \pm 14 \text{ V}, V_D$	$V_S = \pm 14 \text{ V}, V_D = \mp 14 \text{ V}$		-1 -100	±0.1	1 100	nA
Drain On Leakage Current	I _{D(on)}	$V_D = V_S = \pm$	14 V	Room Hot	-11 -100	±0.1	1 100	1
Digital Control	L				1			
Input Current with		V _{IN} = 5 V		Room Full	-1 -1	-0.001		
Input Voltage High	I _{INH}	V _{IN} = 15	V	Room Full		0.001	1	μΑ
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V		Room Full	-1 -1	-0.001		1
Dynamic Characteristic	s	l		<u> </u>	<u> </u>	<u>I</u>		
Turn-On Time	t _{ON}			Room		150	300	
Turn-Off Time	t _{OFF}	See Figur	See Figure 2			130	250	ns
Break-Before-Make Time	t _{OPEN}	See Figure	9 3	Room		50		1
Charge Injection	Q	C _L = 0.01 μF, R _{gen} = 0) Ω V _{gen} = 0 V	Room		10		рС
Source-Off Capacitance	C _{S(off)}		-	Room		14		
Drain-Off Capacitance	C _{D(off)}	f = 1 MHz; V _S , V	/ _D = 0 V	Room		14		pF
Channel-On Capacitance	C _{D(on)}	1		Room		40		
Input Capacitance		f = 1 MHz	V _{IN} = 0 V	Room		6		_
	C _{IN}		V _{IN} = 15 V	Room		7		
Off-Isolation	OIRR			Room		62		
Crosstalk (Channel-to-Channel)	X _{TALK}	$V_{IN} = 0 \text{ V, } R_L = 1 \text{ k}\Omega$ $V_S = 1 \text{ V}_{rms}, f = 500 \text{ kHz}$		Room		74		dB
Power Supplies	•	•				1		·
Positive Supply Current	I+	V _{IN} = 4 V (One Input) (All Others = 0)		Room Full		0.23	0.5 1.0	mA
Negative Supply Current	I–			Room Full	-10 -100	-0.001		
Positive Supply Current	I+	V _{IN} = 0.8 V (All Inputs)		Room Full		0.001	10 100	μΑ
Negative Supply Current	I–			Room Full	-10 -100	-0.001		1

- Notes:

 a. Refer to PROCESS OPTION FLOWCHART.

 b. Room = 25°C, Full = as determined by the operating temperature suffix.

 c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

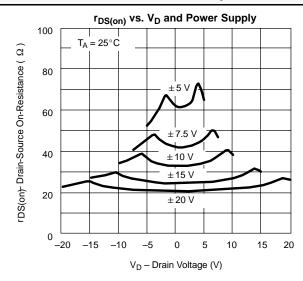
 d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

 e. Guaranteed by design, not subject to production test.

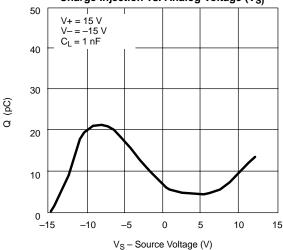
 f. V_{IN} = input voltage to perform proper function.



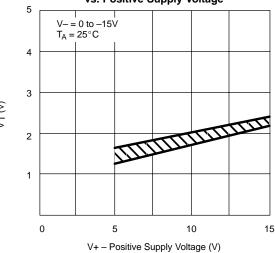
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

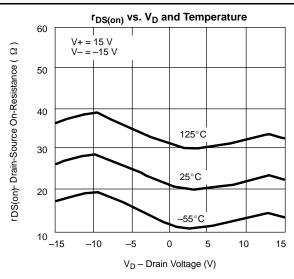




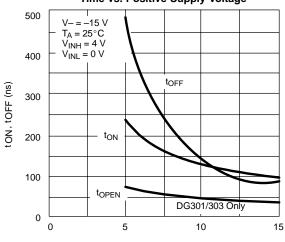


Input Switching Threshold vs. Positive Supply Voltage

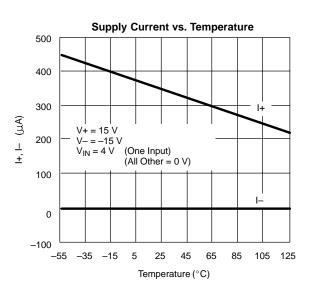




Switching Time and Break-Before-Make Time vs. Positive Supply Voltage

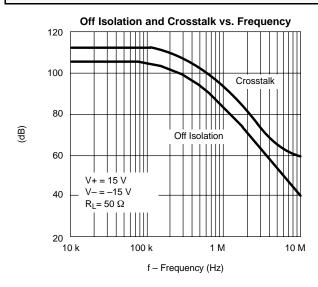


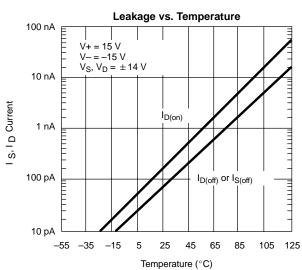
V+ - Positive Supply Voltage (V)

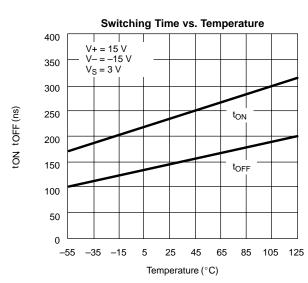


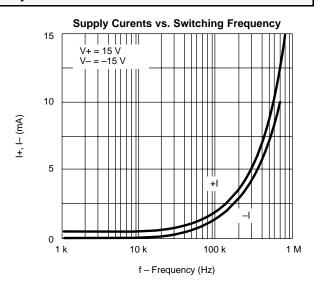


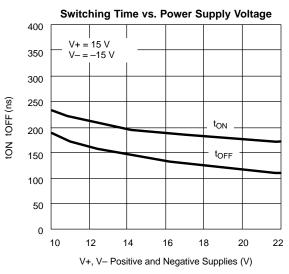
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

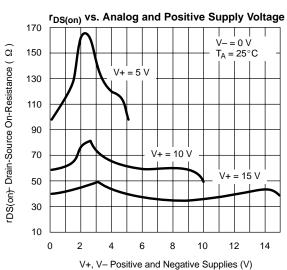














TEST CIRCUITS

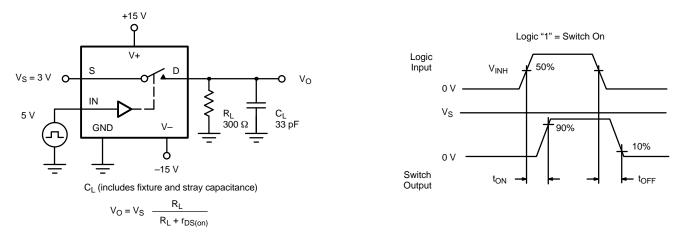


FIGURE 2. Switching Time

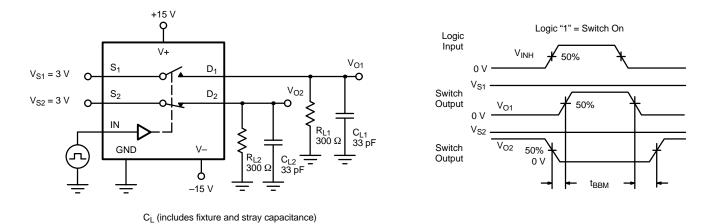


FIGURE 3. Break-Before-Make SPDT

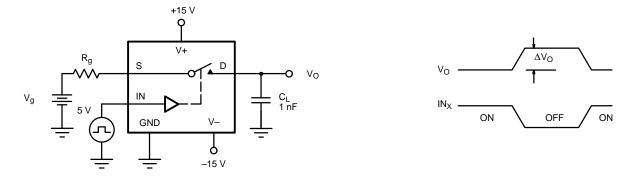


FIGURE 4. Charge Injection



APPLICATIONS

The DG381A_MIL and DG390A_MIL analog switches will switch positive analog signals while using a single positive supply. This allows their use in applications where only one supply is available. The trade-offs or performance given up while using single supplies are: 1) increased $r_{\text{DS(on)}},\,2)$ slower switching speed. Typical curves for aid in designing with single supplies are supplied (see Typical Characteristics). The analog voltage should not go above or below the supply voltages which in single operation are V+ and 0 V.

In the integrator of Figure 4, R_D controls the discharge rate of the capacitor so that the pulsed or continuous current ratings are not exceeded. During reset SW_1 is closed and SW_2 is open. Opening SW_2 with SW_1 also open will hold the integrator output at its present value.

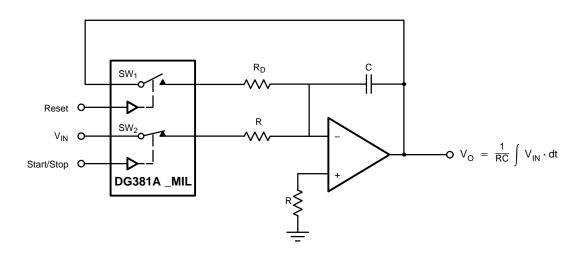


FIGURE 5. Integrator with Reset and Start/Stop



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